Best Available Copy PATENT ABSTRACTS OF JAPAN

(11)Publication number:

52-045295

(43) Date of publication of application: 09.04.1977

(51)Int.Cl.

H01L 29/84

(21)Application number: 50-120653

(71)Applicant: HITACHI LTD

(22)Date of filing:

08.10.1975

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(54) METHOD FOR FABRICATION OF SEMICONDUCTIVE PRESSURE CONVERTER (57) Abstract:

PURPOSE: To increase adhesive strength and tightness by carrying out adhesion of supporting substrate and pressure sensitive Si element with Au-Si cocrystallizing alloy in high purity H2, Ar, or He atmosphere.

LEGAL STATUS

[Date of request for examination]

[Date of sending the examiner's decision of rejection]

[Kind of final disposal of application other than the examiner's decision of rejection or application converted registration]

[Date of final disposal for application]

[Patent number]

[Date of registration]

[Number of appeal against examiner's decision of rejection]

[Date of requesting appeal against examiner's decision of rejection]

[Date of extinction of right]